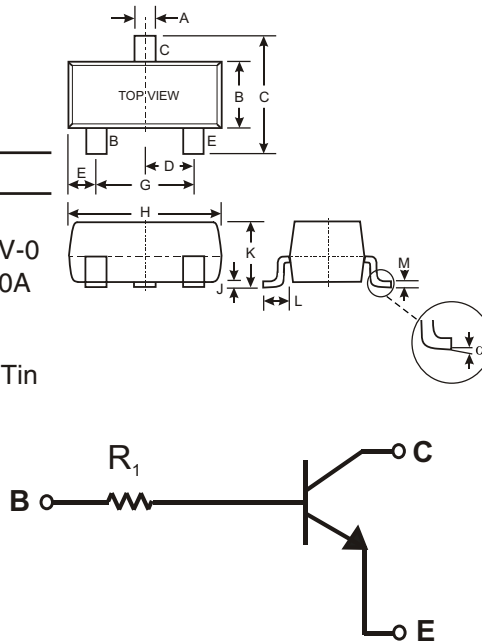


Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTA)
- Built-In Biasing Resistor, R1 only
- Also Available in Lead Free Version

Mechanical Data

- Case: SOT-23, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 3, on Page 2
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Weight: 0.008 grams (approx.)
- Ordering Information (See Page 2)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
α	0°	8°
All Dimensions in mm		

P/N	R1 (NOM)	MARKING
DDTC113TCA	1KΩ	N01
DDTC123TCA	2.2KΩ	N03
DDTC143TCA	4.7KΩ	N07
DDTC114TCA	10KΩ	N12
DDTC124TCA	22KΩ	N16
DDTC144TCA	47KΩ	N19
DDTC115TCA	100KΩ	N23
DDTC125TCA	200KΩ	N25

SCHMATIC DIAGRAM

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	I _C (Max)	100	mA
Power Dissipation	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R _{θJA}	625	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	50	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	5	—	—	V	I _E = 50μA
Collector Cutoff Current	I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cutoff Current	I _{EBO}	—	—	0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	0.3	V	I _C /I _B = 10mA/1mA DDTC113TCA I _C /I _B = 5mA/0.5mA DDTC123TCA I _C /I _B = 2.5mA/.25mA DDTC143TCA I _C /I _B = 1mA/.1mA DDTC114TCA I _C /I _B = 5mA/0.5mA DDTC124TCA I _C /I _B = 2.5mA/.25mA DDTC144TCA I _C /I _B = 1mA/0.1mA DDTC115TCA I _C /I _B = .5mA/.05mA DDTC125TCA
DC Current Transfer Ratio	h _{FE}	100	250	600	—	I _C = 1mA, V _{CE} = 5V
Input Resistor (R ₁) Tolerance	ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product*	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

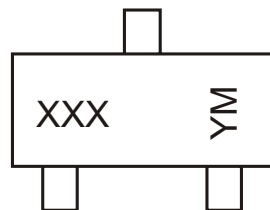
* Transistor - For Reference Only

Ordering Information

Device	Packaging	Shipping
DDTC113TCA-7	SOT-23	3000/Tape & Reel
DDTC123TCA-7	SOT-23	3000/Tape & Reel
DDTC143TCA-7	SOT-23	3000/Tape & Reel
DDTC114TCA-7	SOT-23	3000/Tape & Reel
DDTC124TCA-7	SOT-23	3000/Tape & Reel
DDTC144TCA-7	SOT-23	3000/Tape & Reel
DDTC115TCA-7	SOT-23	3000/Tape & Reel
DDTC125TCA-7	SOT-23	3000/Tape & Reel

- Notes: 2. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
 3. For Lead Free version (with Lead Free terminal finish) part number, please add "-F" suffix to part number above.
 Example: DDTC125TCA-7-F.

Marking Information



XXX = Product Type Marking Code
 See Sheet 1 Diagrams
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DDTC114TCA

NEW PRODUCT

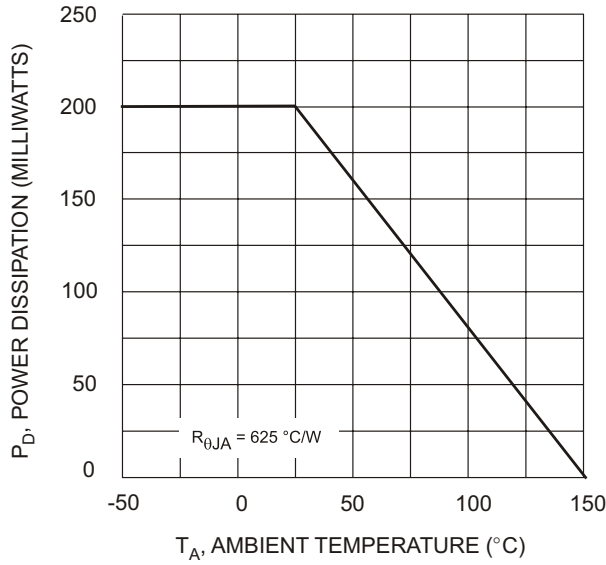


Fig. 1 Derating Curve

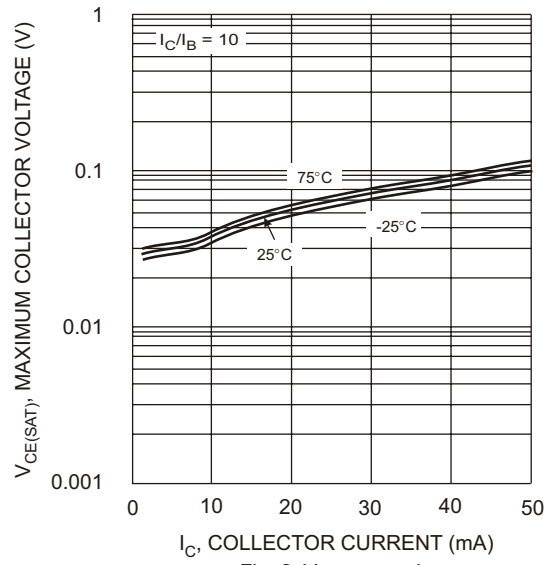


Fig. 2 $V_{CE(SAT)}$ vs. I_C

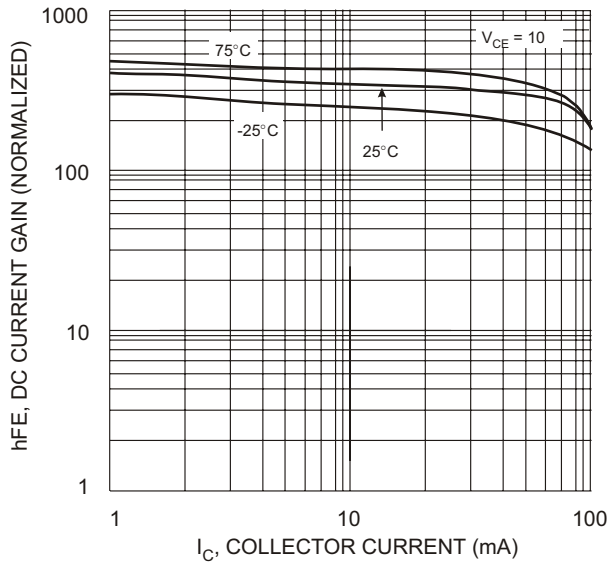


Fig. 3 DC Current Gain

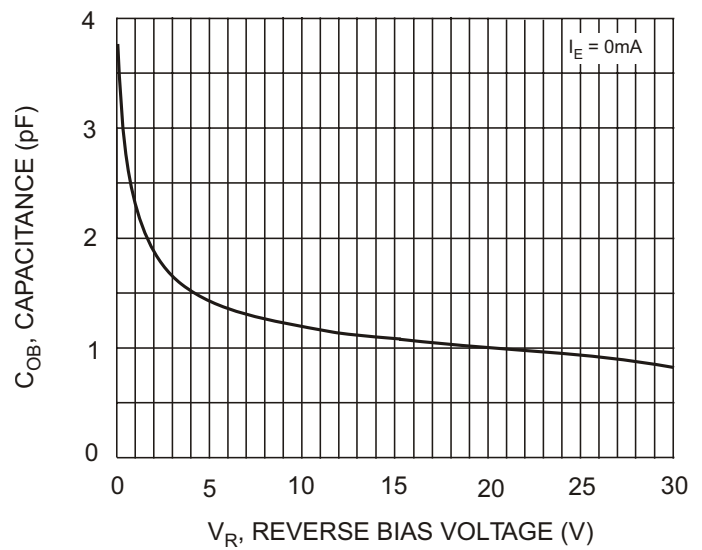


Fig. 4 Output Capacitance

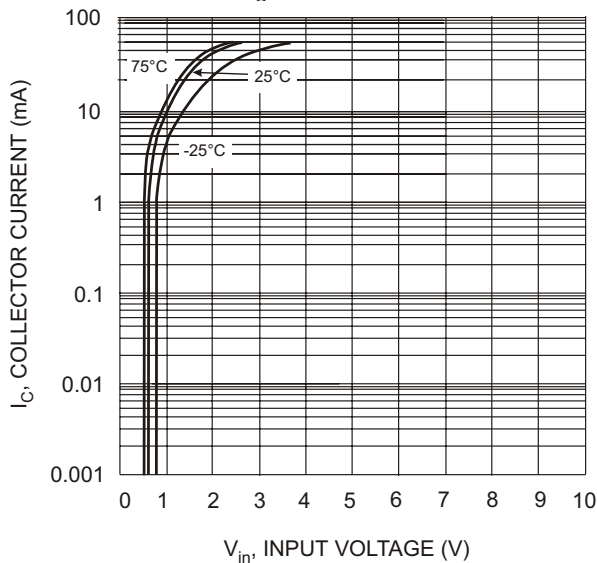


Fig. 5 Collector Current Vs. Input Voltage

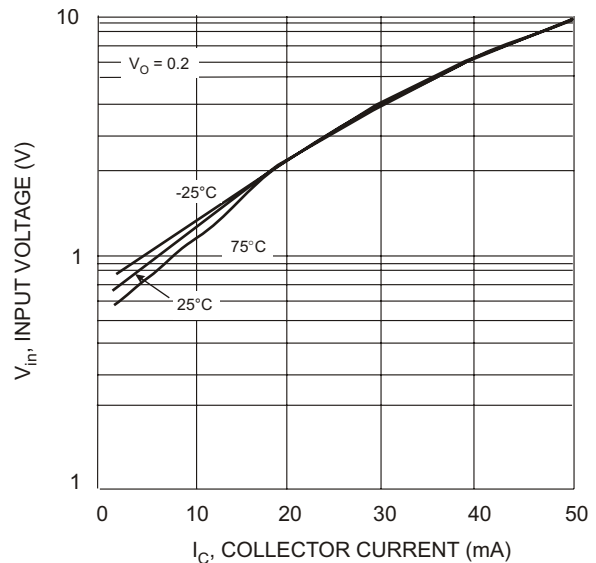


Fig. 6 Input Voltage vs. Collector Current